Vishay Semiconductors





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AAP Gen 7 (TO-240AA)

| PRIMARY CHARACTERISTICS | | | |
|-------------------------|----------------------------|--|--|
| I _{F(AV)} | 110 A | | |
| V _R | 30 V | | |
| Package | AAP Gen 7 (TO-240AA) | | |
| Circuit configuration | Two diodes doubler circuit | | |

MECHANICAL DESCRIPTION

The AAP Gen 7, new generation of ADD-A-PAK module, combines the excellent thermal performances obtained by the usage of exposed direct bonded copper substrate, with advanced compact simple package solution and simplified internal structure with minimized number of interfaces.

FEATURES

- 150 °C T_J operation
- Low forward voltage drop
- High frequency operation
- Low thermal resistance
- UL approved file E78996
- Designed and qualified for industrial level
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

BENEFITS

- Excellent thermal performances obtained by the usage of exposed direct bonded copper substrate
- High surge capability
- Easy mounting on heatsink

ELECTRICAL DESCRIPTION / APPLICATIONS

The VS-VSKDS220.. Schottky rectifier doubler has been optimized for low reverse leakage at high temperature. The proprietary barrier technology allows for reliable operation up to 150 °C junction temperature.

Typical applications are in high current switching power supplies, plating power supplies, UPS systems, converters, freewheeling diodes, welding, and reverse battery protection.

| MAJOR RATINGS AND CHARACTERISTICS | | | | | |
|-----------------------------------|---|-------------|-------|--|--|
| SYMBOL | CHARACTERISTICS | VALUES | UNITS | | |
| I _{F(AV)} | Rectangular waveform | 110 | А | | |
| V _{RRM} | | 30 | V | | |
| I _{FSM} | t _p = 5 μs sine | 18 000 | А | | |
| V _F | 110 A _{pk} , T _J = 125 °C | 0.57 | V | | |
| TJ | Range | -55 to +150 | C° | | |

| VOLTAGE RATINGS | | | |
|--------------------------------------|------------------|-----------------|-------|
| PARAMETER | SYMBOL | VS-VSKDS220/030 | UNITS |
| Maximum DC reverse voltage | V _R | 30 | V |
| Maximum working peak reverse voltage | V _{RWM} | 50 | v |



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| ABSOLUTE MAXIMUM RATIN | GS | | | | |
|---------------------------------|--------------------|---|---|--------|-------|
| PARAMETER | SYMBOL | TEST CONDI | TIONS | VALUES | UNITS |
| Maximum average forward current | I _{F(AV)} | 50 % duty cycle at T_{C} = 110 °C | , rectangular waveform | 110 | |
| Maximum peak one cycle | | 5 μs sine or 3 μs rect. pulse | Following any rated load condition and with | 18 000 | А |
| non-repetitive surge current | IFSM | 10 ms sine or 6 ms rect. pulse | rated V _{RRM} applied | 2000 | |
| Non-repetitive avalanche energy | E _{AS} | $T_J = 25 \text{ °C}, I_{AS} = 15 \text{ A}, L = 1 \text{ mH}$ 9 | | 99 | mJ |
| Repetitive avalanche current | I _{AR} | Current decaying linearly to zer Frequency limited by T_J maxim | | 22 | А |

| ELECTRICAL SPECIFICATION | IS | | | | |
|---------------------------------|--|--|---------------------------------------|--------|-------|
| PARAMETER | SYMBOL | TEST CO | NDITIONS | VALUES | UNITS |
| | $V_{FM} = \begin{array}{c} 110 \text{ A} \\ \hline 220 \text{ A} \\ \hline 110 \text{ A} \\ \hline 110 \text{ A} \\ \hline T_{J} = 25 \text{ °C} \\ \hline T_{J} = 125 \text{ °C} \\ \hline \end{array}$ | 110 A | T _J = 25 °C | 0.59 | v |
| Maximum forward voltage drop | | 220 A | | 0.78 | |
| Maximum forward voltage drop | | T 405.00 | 0.57 | v | |
| | | 220 A | 1j = 125 C | 0.82 | |
| Maximum reverse lookage averant | rse leakage current | T _J = 25 °C | V _R = Rated V _R | 10 | mA |
| Maximum reverse leakage current | | T _J = 125 °C | | 650 | mA |
| Maximum junction capacitance | CT | $V_{R} = 5 V_{DC}$ (test signal range 100 kHz to 1 MHz), 25 °C | | 7400 | pF |
| Typical series inductance | L _S | Measured lead to lead 5 mm from package body | | 7.0 | nH |
| Maximum voltage rate of change | dV/dt | Rated V _R 100 | | 10 000 | V/µs |
| Maximum RMS insulation voltage | V _{INS} | 50 Hz 3000 (1 min) 3600 (1 s) | | V | |

| THERMAL - MECHAN | CAL SPE | CIFICATI | ONS | | |
|---|-------------|-----------------------------------|--|-------------|----------|
| PARAMETER | | SYMBOL | TEST CONDITIONS | VALUES | UNITS |
| Maximum junction and storage temperature range | | T _J , T _{Stg} | | -55 to +150 | °C |
| Maximum thermal resistance, junction to case per leg | | R _{thJC} | DC operation | 0.52 | °C/W |
| Typical thermal resistance, case to heatsink per module | | R _{thCS} | | 0.1 | 0/10 |
| Approvimato weight | | | | 75 | g |
| Approximate weight | | | | 2.7 | oz. |
| Mounting torque ± 10 % | to heatsink | | A mounting compound is recommended and the torque should be rechecked after a period of 3 h to allow for the | 4 | Nm |
| | busbar | | spread of the compound. | | |
| Case style | | | JEDEC® | TO-240AA co | mpatible |

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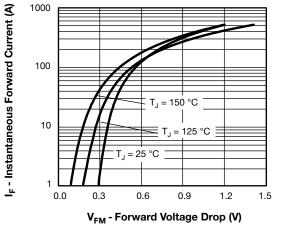
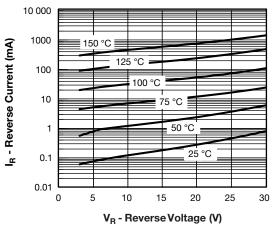
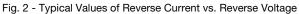


Fig. 1 - Maximum Forward Voltage Drop Characteristics





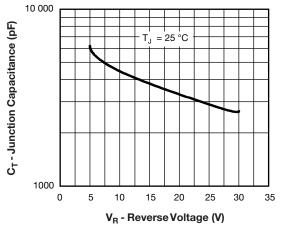


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

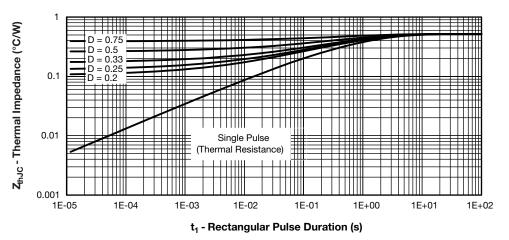


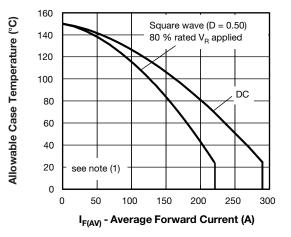
Fig. 4 - Maximum Thermal Impedance ZthJC Characteristics

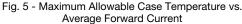
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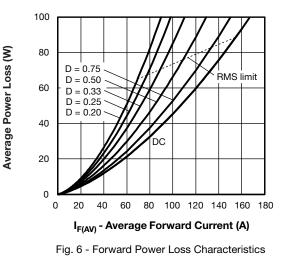
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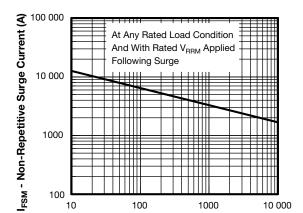


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t_p - Square Wave Pulse Duration (μs)

Fig. 7 - Maximum Non-Repetitive Surge Current

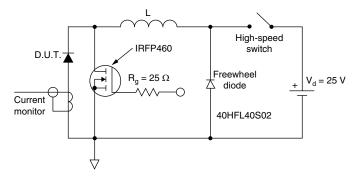


Fig. 8 - Unclamped Inductive Test Circuit

Note

- ⁽¹⁾ Formula used: $T_C = T_J (Pd + Pd_{REV}) \times R_{thJC}$;
 - $\begin{array}{l} \mathsf{Pd} = \mathsf{forward} \ \mathsf{power} \ \mathsf{loss} = \mathsf{I}_{\mathsf{F}(\mathsf{AV})} \times \mathsf{V}_{\mathsf{FM}} \ \mathsf{at} \ (\mathsf{I}_{\mathsf{F}(\mathsf{AV})}/\mathsf{D}) \ (\mathsf{see} \ \mathsf{fig.} \ \mathsf{6}); \\ \mathsf{Pd}_{\mathsf{REV}} = \mathsf{inverse} \ \mathsf{power} \ \mathsf{loss} = \mathsf{V}_{\mathsf{R1}} \times \mathsf{I}_{\mathsf{R}} \ (\mathsf{1} \mathsf{D}); \ \mathsf{I}_{\mathsf{R}} \ \mathsf{at} \ \mathsf{V}_{\mathsf{R1}} = \mathsf{80} \ \% \ \mathsf{rated} \ \mathsf{V}_{\mathsf{R}} \end{array}$

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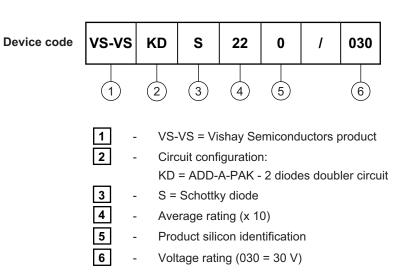
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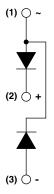
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ORDERING INFORMATION TABLE



CIRCUIT CONFIGURATION



| | ENTS |
|------------|--------------------------|
| Dimensions | www.vishay.com/doc?95369 |

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ADD-A-PAK Generation VII - Diode

DIMENSIONS in millimeters (inches)





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